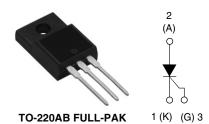




Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 25 A



PRODUCT SUMMARY			
V _T at 16 A < 1.25 V			
I _{TSM}	300 A		
V _{RRM}	800/1200 V		

DESCRIPTION/FEATURES

The 25TTS...FP High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

The fully isolated package ($V_{INS} = 2500 \ V_{RMS}$) is UL E78996 approved. Plastic material $94V_{Ro}$.

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS		
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	18	22	А		

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	16	Λ	
I _{RMS}		25	Α	
V_{RRM}/V_{DRM}		800/1200	V	
I _{TSM}		300	А	
V _T	16 A, T _J = 25 °C	1.25	V	
dV/dt		500	V/µs	
dl/dt		150	A/μs	
TJ		- 40 to 125	°C	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
25TTS08FP	800	10			
25TTS12FP	1200	1200	10		

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	LINUTO
		TEST CONDITIONS	TYP. MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 85 °C, 180° conduction half sine wave	16	
Maximum RMS on-state current	I _{RMS}		25	_
Maximum peak, one-cycle,	-	10 ms sine pulse, rated V _{RRM} applied	300	_ A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	350	
Maximum 12t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	450	A ² s
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied	630	A-S
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied	6300	A²√s
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C	1.25	V
On-state slope resistance	r _t	T _{.I} = 125 °C	12.0	mΩ
Threshold voltage	$V_{T(TO)}$	- 1j= 125 C	1.0	V
Maximum rayaraa and direct lookaga aurrant	1 /1	$T_J = 25 ^{\circ}C$	0.5	
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	10	mA
Holding current	I _H	Anode supply = 6 V, resistive load, initial I _T = 1 A	- 100	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load	200	
Maximum rate of rise of off-state voltage	dV/dt		500	V/µs
Maximum rate of rise of turned-on current	dl/dt		150	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P_{GM}		8.0	W
Maximum average gate power	$P_{G(AV)}$		2.0	
Maximum peak positive gate current	+ I _{GM}		1.5	Α
Maximum peak negative gate voltage	- V _{GM}		10	٧
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	60	mA
		Anode supply = 6 V, resistive load, T _J = 25 °C	45	
		Anode supply = 6 V, resistive load, T _J = 125 °C	20	
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 10 °C	2.5	
		Anode supply = 6 V, resistive load, T _J = 25 °C	2.0	V
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0]
Maximum DC gate voltage not to trigger	V_{GD}	T = 195 °C V = Beted value	0.25	
Maximum DC gate current not to trigger	I_{GD}	$T_J = 125 ^{\circ}\text{C}, V_{DRM} = \text{Rated value}$ 2.		mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs
Typical turn-off time	t _q	1 _J = 125 C	110] .



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PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J , T_{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	1.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque —	minimum			6 (5)	kgf · cm
	maximum			12 (10)	(lbf · in)
Manifelia			Occasional TO COOME FULL DAY (OANO)	25TTS0	BFP
Marking device			Case style TO-220AB FULL-PAK (94/V0)	25TTS1:	2FP

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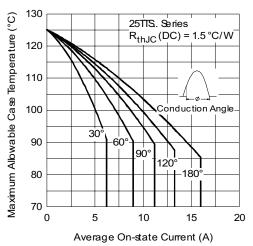


Fig. 1 - Current Rating Characteristics

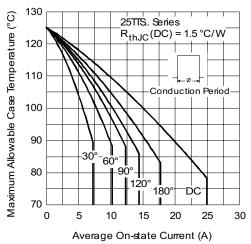


Fig. 2 - Current Rating Characteristics

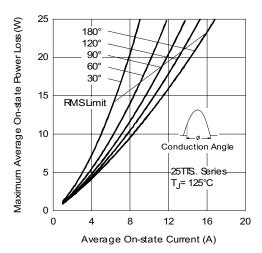


Fig. 3 - On-State Power Loss Characteristics

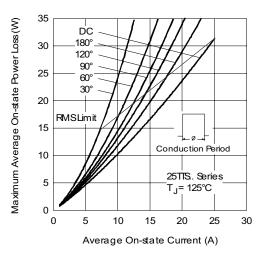
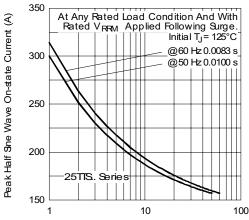


Fig. 4 - On-State Power Loss Characteristics



Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

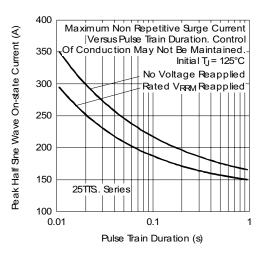


Fig. 6 - Maximum Non-Repetitive Surge Current



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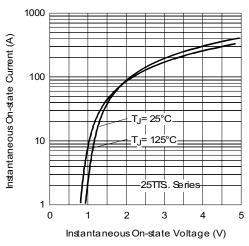


Fig. 7 - On-State Voltage Drop Characteristics

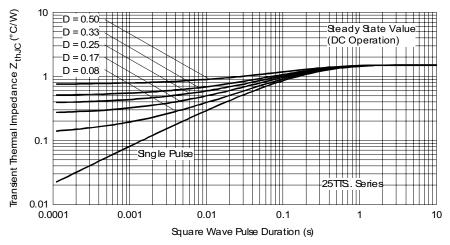


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

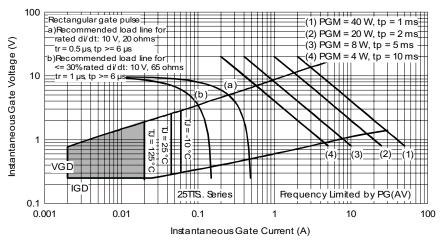


Fig. 9 - Gate Characteristics

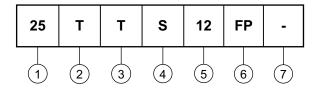
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ORDERING INFORMATION TABLE

Device code



- 1 Current rating (25 = 25 A)
- 2 Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AB

4 - Type of silicon:

Standard recovery rectifier

- 6 FULL-PAK
- None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95072			
Part marking information	http://www.vishay.com/doc?95069		



Vishay

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